## NSN 5961-00-172-4970

Diode Semiconductor Device - Page 1 of 1



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nclosure Material:
Glass
Overall Length:
Between 0.293 inches and 0.357 inches
Terminal Length:
Between 1.000 inches and 1.625 inches
Overall Diameter:
Between 0.215 inches and 0.235 inches
End Application:
Helicopter, mh-53e; communications systems an/wsc-3; ground mobile force satellite comm term (an/tsc-93a); helicopter, advance attack,
ah-1w; countermeasure set, an/alq-15 (v)1; tactical air opns module (an/tyq-(23)); support equipment, b-1 aircraft; support equipment,
o-52 aircraft; aircraft, (ac-
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.5 reverse voltage, dc
Current Rating Per Characteristic:
200.00 amperes forward current, average preset
Power Rating Per Characteristic:
1500.00 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Special Features:
Weapon system essential
Test Data Document:
31349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
31349-mil-s-19500/434 government specification
Shelf Life:
N/a
Unit Of Measure:

No

Demilitarization: